



THE DATASHEET OF SIDC85D170HX1SA2



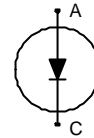
Fast switching diode chip in EMCON 3-Technology

FEATURES:

- 1700V EMCON 3 technology 200 µm chip
- soft, fast switching
- low reverse recovery charge
- small temperature coefficient

This chip is used for:

- EUPEC power modules



Applications:

- resonant applications, drives

Chip Type	V _R	I _F	Die Size	Package	Ordering Code
SIDC85D170H	1700V	150A	9.2 x 9.2 mm ²	sawn on foil	Q67050-A4178-A001

MECHANICAL PARAMETER:

Raster size	9.2 x 9.2	mm ²
Area total / active	84.64 / 67.8	
Anode pad size	7.18 x 7.18	
Thickness	200	µm
Wafer size	150	mm
Flat position	180	deg
Max. possible chips per wafer	160 pcs	
Passivation frontside	Photoimide	
Anode metallization	3200 nm Al Si Cu	
Cathode metallization	Ni Ag –system suitable for epoxy and soft solder die bonding	
Die bond	electrically conductive glue or solder	
Wire bond	Al, ≤500µm	
Reject Ink Dot Size	Ø 0.65mm; max 1.2mm	
Recommended Storage Environment	store in original container, in dry nitrogen, < 6 month at an ambient temperature of 23°C	

Maximum Ratings

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	V_{RRM}		1700	V
Continuous forward current limited by T_{jmax}	I_F		150	A
Single pulse forward current (depending on wire bond configuration)	I_{FSM}	$t_p = 10 \text{ ms sinusoidal}$	740	
Maximum repetitive forward current limited by T_{jmax}	I_{FRM}		300	
Operating junction and storage temperature	T_j, T_{stg}		-55...+150	°C

Static Electrical Characteristics (tested on chip), $T_j=25^\circ\text{C}$, unless otherwise specified

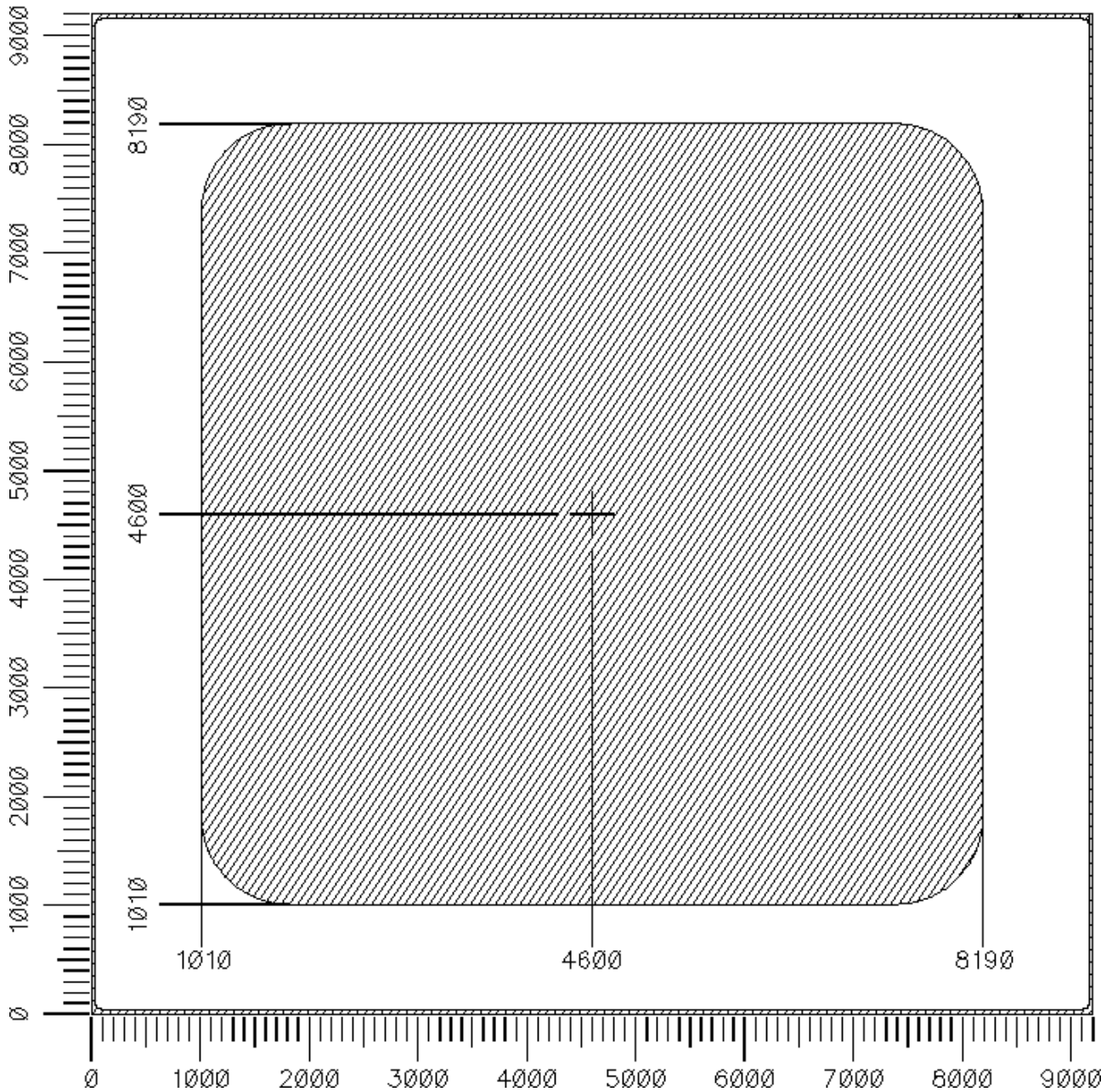
Parameter	Symbol	Conditions		Value			Unit
				min.	Typ.	max.	
Reverse leakage current	I_R	$V_R=1700\text{V}$	$T_j=25^\circ\text{C}$			27	μA
Cathode-Anode breakdown Voltage	V_{Br}	$I_R=0.25\text{mA}$	$T_j=25^\circ\text{C}$	1700			V
Forward voltage drop	V_F	$I_F=150\text{A}$	$T_j=25^\circ\text{C}$		1.8		V

Dynamic Electrical Characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified, tested at component

Parameter	Symbol	Conditions		Value			Unit
				min.	Typ.	max.	
Peak recovery current	I_{RRM1}	$I_F=150\text{A}$	$T_j = 25^\circ\text{C}$		131		A
	I_{RRM2}	$di/dt=770\text{A/ms}$ $V_R=900\text{V}$	$T_j = 125^\circ\text{C}$		158		
Reverse recovery charge	Q_{rr1}	$I_F=150\text{A}$	$T_j=25^\circ\text{C}$		35.8		μC
	Q_{rr2}	$di/dt=770\text{A/ms}$ $V_R=900\text{V}$	$T_j=125^\circ\text{C}$		62.3		
Peak recovery energy	E_{rec1}	$I_F=150\text{A}$	$T_j=25^\circ\text{C}$		24.2		mJ
	E_{rec2}	$di/dt=770\text{A/ms}$ $V_R=900\text{V}$	$T_j=125^\circ\text{C}$		42.9		

CHIP DRAWING:

L449A1



FURTHER ELECTRICAL CHARACTERISTICS:

This chip data sheet refers to the device data sheet

INFINEON TECHNOLOGIES /
EUPEC

tbd

Description:

AQL 0,65 for visual inspection according to failure catalog

Electrostatic Discharge Sensitive Device according to MIL-STD 883

Test-Normen Villach/Prüffeld

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